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Amendments to the Claims

This listing of claims replaces all previous versions and listings of the claims.

Listing of Claims:

1.-13. (Cancelled)

- 14. (Currently Amended) An article comprising recrystallized eeramic material selected from the group consisting of silicon carbide, silicon nitride, and aluminum oxide, the ceramic material having a pore size of at least about 15 μm and comprising an impurityimpurities at a concentration of less than 1 ppm, wherein the impurity is one of iron, copper, nickel, chromium, and calcium about 400 ppm.
- 15. (Currently Amended) The article of claim 14, wherein the <u>impurity is an</u> active impurity that can migrate to a semiconductor wafer during semiconductor wafer processing.

16.-22. (Cancelled)

- (Currently Amended) The article of claim 14, wherein the <u>recrystallized</u> silicon carbide further comprises inert impurities.
- 24. (Previously Presented) The article of claim 14, wherein the article is a wafer boat.

25,-29, (Cancelled)

30. (Currently Amended) An article A wafer boat comprising recrystallized silicon carbide having pores interconnected to form a network and comprising an active impurity component at a concentration of less than 1 ppm, wherein the active impurity component is one of iron, copper, nickel, chromium, and calcium.

- 31. (Previously Presented) The article of claim 30, wherein the article is a wafer boat.
- (Previously Presented) The article of claim 30 wherein the pores have a pore size of at least about 15 um.
- (Currently Amended) An article comprising a recrystallized silicon carbide member having [[a]]an interconnected network of pores that have a pore size of at least about 5 µm and comprising impurities at a concentration of less than about 400 ppm.
- 34. (Previously Presented) The article of claim 33, wherein the silicon carbide member is free of free silicon.
- (Previously Presented) The article of claim 33, wherein the silicon carbide member has a
 Fe concentration at or below 2 ppm.
- (Previously Presented) The article of claim 33, wherein the silicon carbide member has a Ni concentration at or below 5 ppm.
- (Cancelled)
- 38. (Withdrawn) A ceramic article comprising:
- recrystallized silicon carbide having an interconnected network of pores with a pore size of at least about $5 \, \mu m$; and
 - an oxide layer on at least a portion of at least one surface of the ceramic article,
- wherein the recrystallized silicon carbide has an impurity selected from the consisting of iron, copper, nickel, chromium, and calcium, at a concentration of less than 1 ppm.

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39. (Withdrawn) The ceramic article of claim 38, wherein the recrystallized silicon carbide is free of free silicon.

- (Withdrawn) The ceramic article of claim 38, wherein the recrystallized silicon carbide has a pore surface area of less than about 0.04 m²/gr.
- 41. (Withdrawn) The ceramic article of claim 38, wherein the oxide layer comprises aluminum oxide.